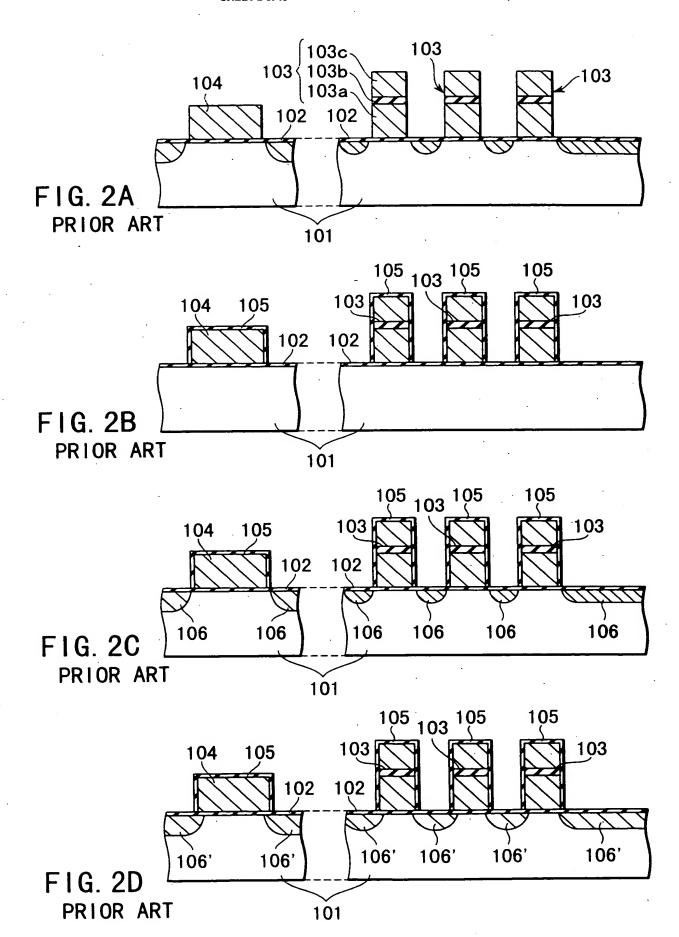


FIG. 1 PRIOR ART



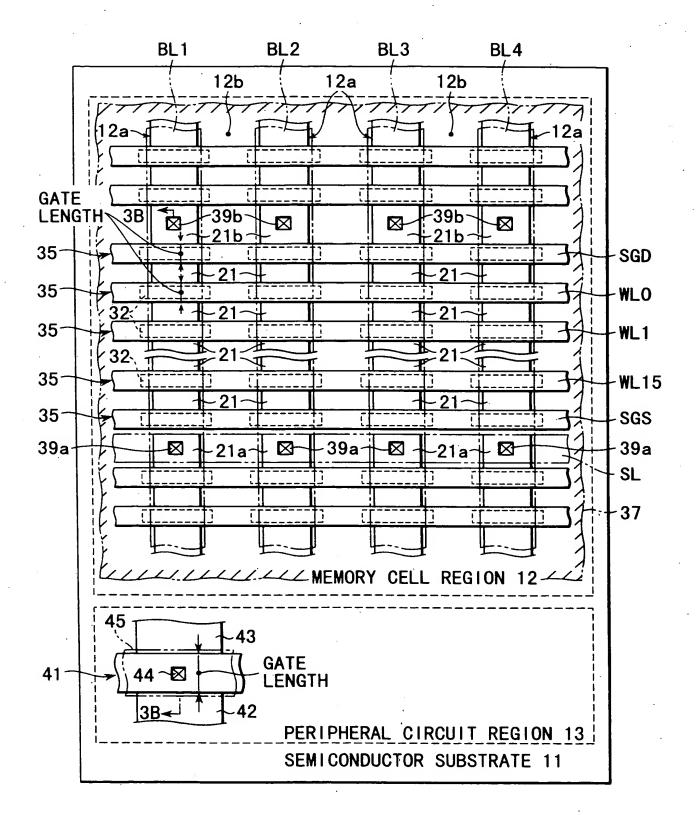
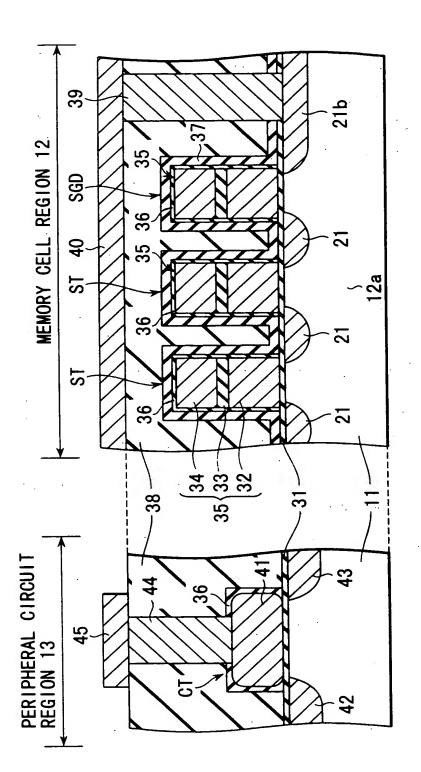


FIG. 3A



F1G. 3B

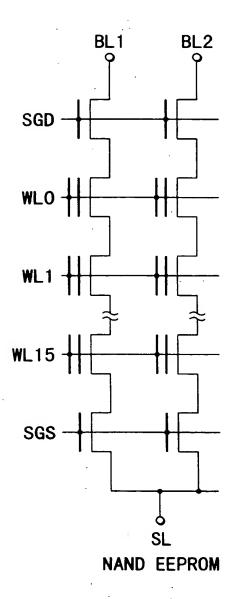
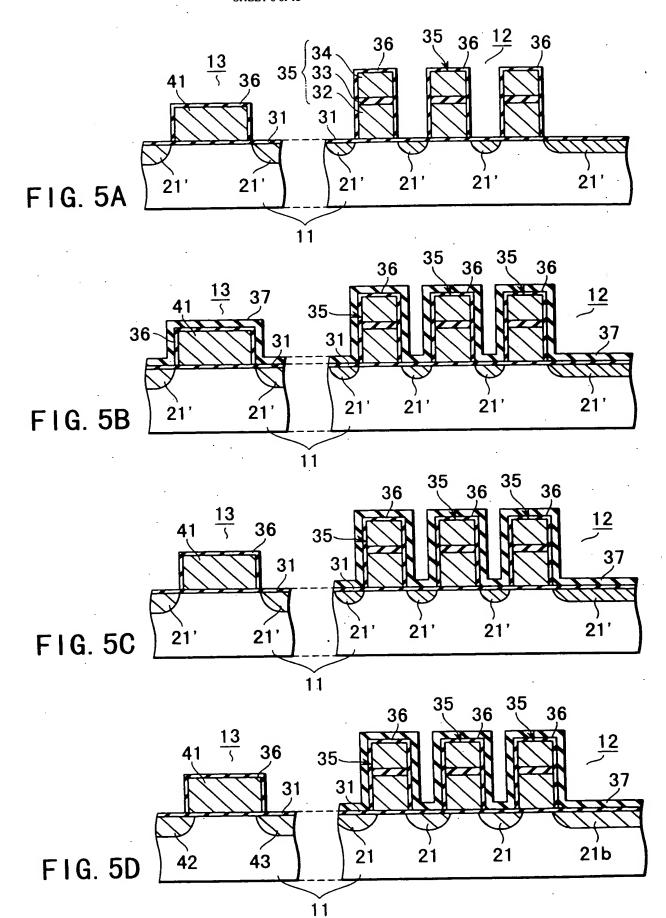
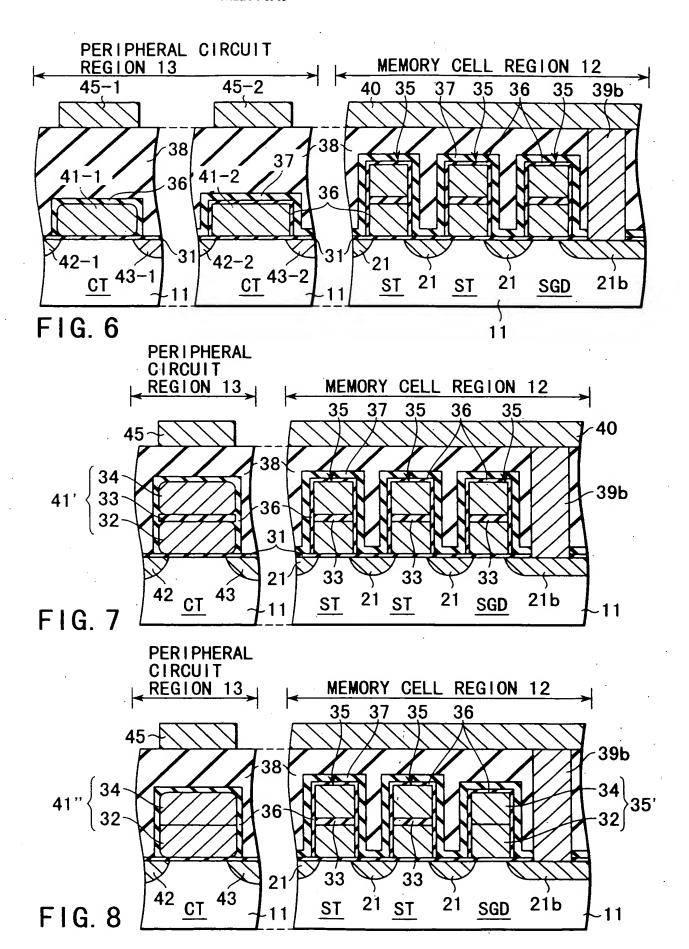
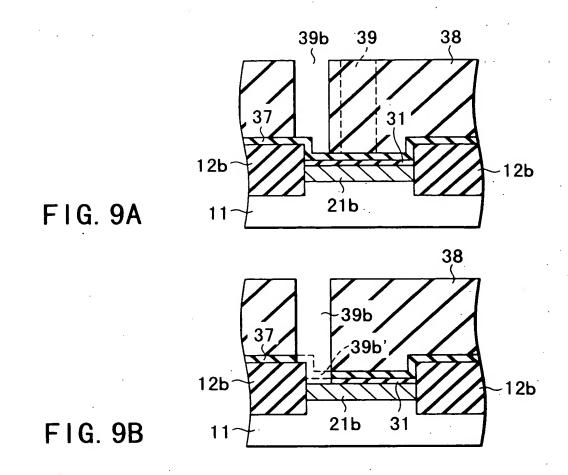


FIG. 4







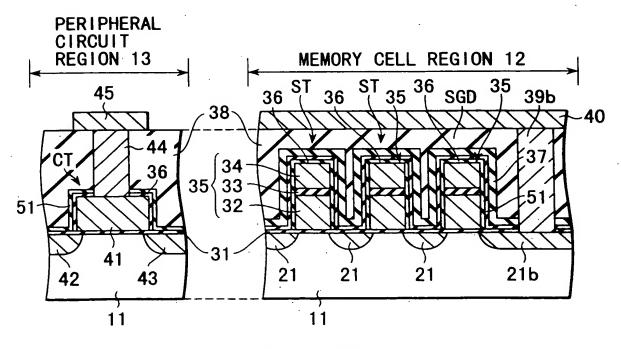
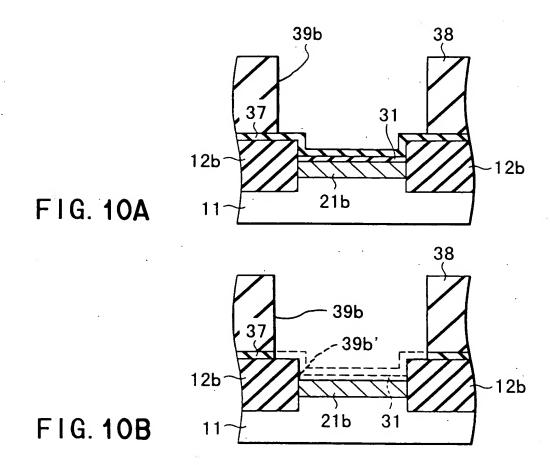


FIG. 12



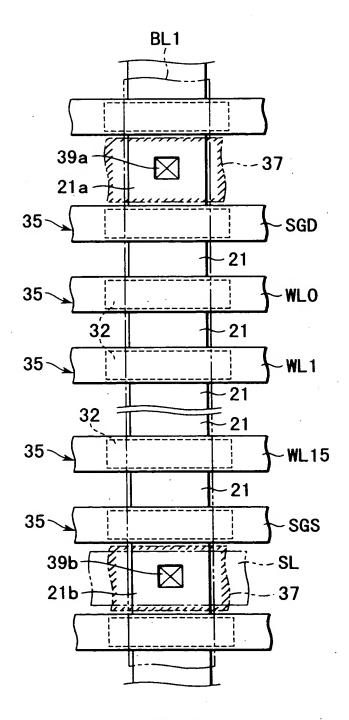
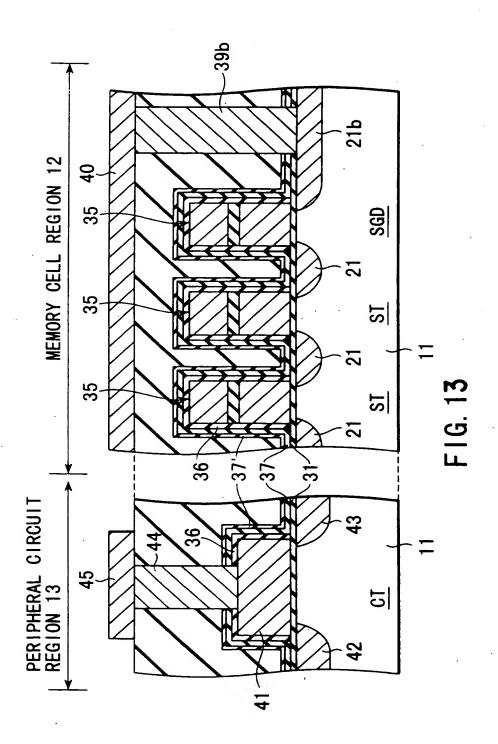
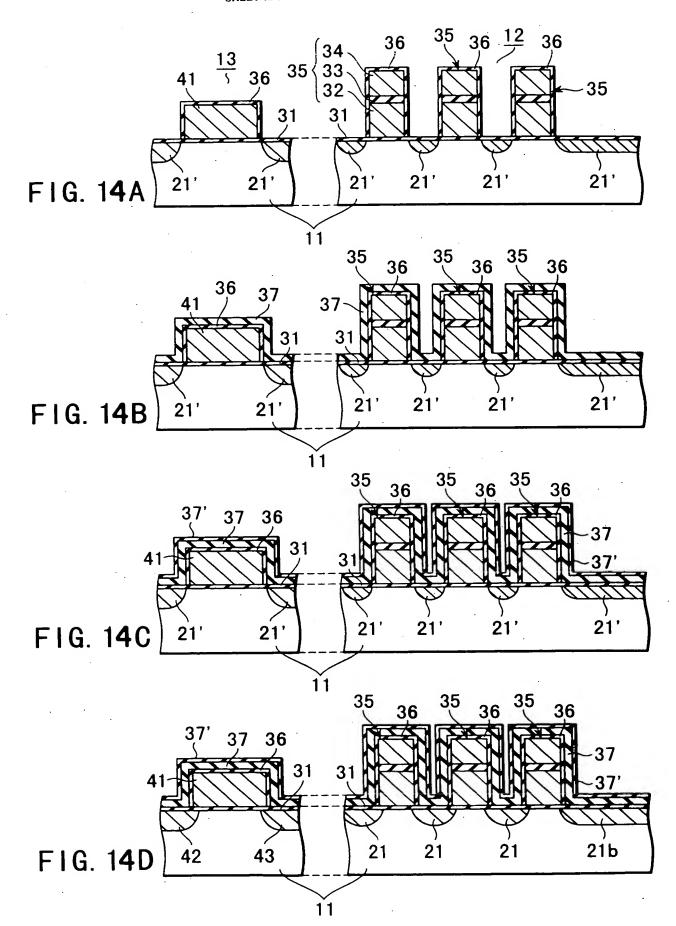


FIG. 11





	CONCENTRATION OF HYDROGEN IN SIN FILM	CONCENTRATION OF HYDROGEN IN TUNNEL OXIDE FILM	dVg (ELECTRON AMOUNT TRAP)
NO SURFACE OXIDE FILM	$4.0 \times 10^{21}$ $atom/cm^3$	1	512mV
SURFACE OXIDE FILM FORMED	1.6×10 <sup>21</sup> atom/cm <sup>3</sup>	0. 2	398mV

FIG. 15

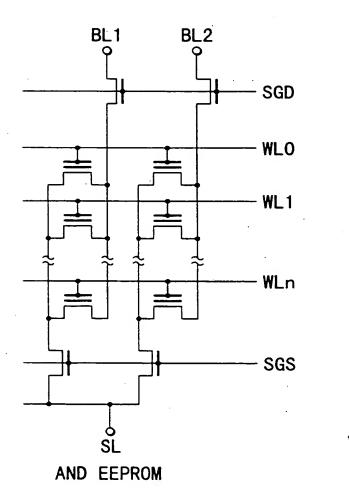


FIG. 16A

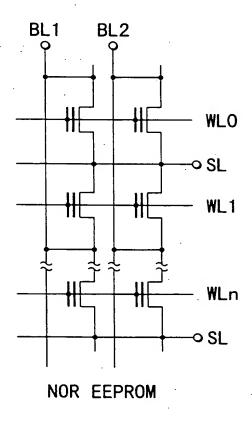


FIG. 16B